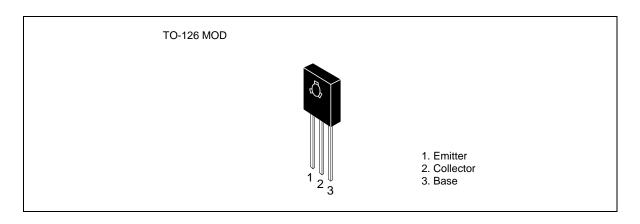
Silicon PNP Epitaxial

HITACHI

Application

Low frequency power amplifier complementary pair with 2SD669/A

Outline



Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

		Ratings			
Item	Symbol	2SB649	2SB649A	Unit	
Collector to base voltage	V _{CBO}	-180	-180	V	
Collector to emitter voltage	V _{CEO}	-120	-160	V	
Emitter to base voltage	$V_{\scriptscriptstyle{EBO}}$	- 5	– 5	V	
Collector current	I _c	-1.5	-1.5	А	
Collector peak current	I _{C(peak)}	-3	- 3	А	
Collector power dissipation	P _c	1	1	W	
	P _c *1	20	20	W	
Junction temperature	Tj	150	150	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	°C	

Note: 1. Value at $T_c = 25^{\circ}C$

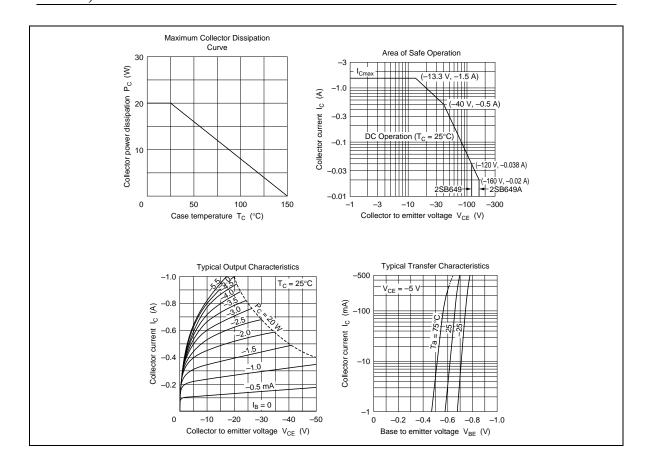
Electrical Characteristics (Ta = 25°C)

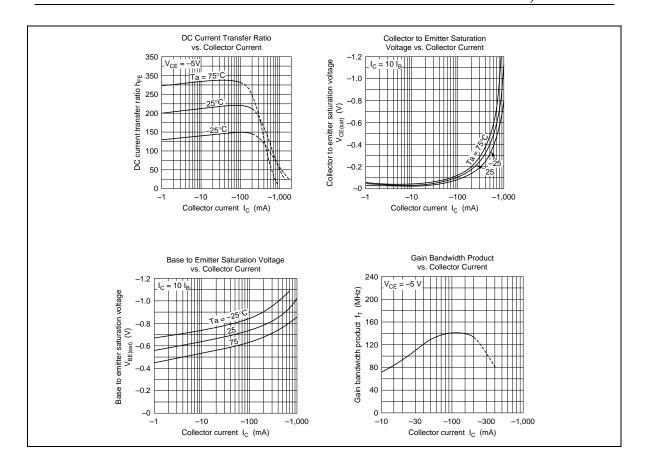
		2SB6	49	9 2SB649A					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-180	_	_	-180	_	_	V	$I_{c} = -1 \text{ mA}, I_{E} = 0$
Collector to emitter breakdown voltage	$V_{\scriptscriptstyle (BR)CEO}$	-120	_	_	-160	_	_	V	$I_{c} = -10 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{\text{(BR)EBO}}$	- 5	_	_	– 5	_	_	V	$I_{\rm E} = -1$ mA, $I_{\rm C} = 0$
Collector cutoff current	I _{CBO}	_	_	-10	_	_	-10	μΑ	$V_{CB} = -160 \text{ V}, I_{E} = 0$
DC current transfer ratio	h _{FE1} *1	60	_	320	60	_	200		$V_{ce} = -5 \text{ V},$ $I_{c} = -150 \text{ mA}$
	h _{FE2}	30	_	_	30	_	_		$V_{CE} = -5 \text{ V},$ $I_{C} = -500 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{\scriptscriptstyle{CE(sat)}}$	_	_	– 1	_	_	– 1	V	$I_{c} = -500 \text{ mA},$ $I_{B} = -50 \text{ mA}$
Base to emitter voltage	V_{BE}	_	_	-1.5	_	_	-1.5	V	$V_{CE} = -5 \text{ V},$ $I_{C} = -150 \text{ mA}$
Gain bandwidth product	f _T		140			140		MHz	$V_{ce} = -5 \text{ V},$ $I_{c} = -150 \text{ mA}$
Collector output capacitance	Cob	_	27	_	_	27	_	pF	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz

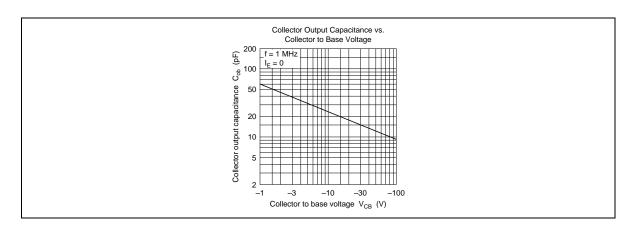
Notes: 1. The 2SB649 and 2SB649A are grouped by h_{FE1} as follows.

2. Pulse test

	В	С	D
2SB649	60 to 120	100 to 200	160 to 320
2SB649A	60 to 120	100 to 200	_







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HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
Nippon Bidg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100, Japan Tel: Tokyo (03) 3270-2111
Fax: (03) 3270-5109

For further information write to:
Hitachi America, Ltd.
Semiconductor & IC Div.
2000 Sierra Point Parkway
Brisbane, CA. 94005-1835
U S A
U S A
Tel: 415-589-8300
Fax: 415-583-4207
Fax: 298-9 29 180-0
Fax: 298-9 29 30 0 0 München Tel: 089-9 91 80-0 Fax: 089-9 29 30 00

Hitachi Europe Ltd.
Electronic Components Div.
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel: 0628-585000
Fax: 0628-778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 0104 Tel: 535-2100 Fax: 535-1533

Hitachi Asia (Hong Kong) Ltd. Unit 706, North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon Hong Kong Tel: 27359218 Fax: 27306071